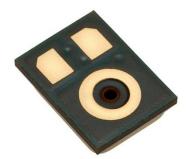


Low Noise Zero-Height SiSonicTM Microphone





The SPA2629LR5H-B is a miniature, high-performance, low power, bottom port silicon microphone. Using Knowles' proven high performance SiSonicTM MEMS technology, the SPA2629LR5H-B consists of an acoustic sensor, a low noise input buffer, and an output amplifier. These devices are suitable for applications such as cellphones, smart phones, laptop computers, sensors, digital still cameras, portable music recorders, and other portable electronic devices where excellent wideband audio performance and RF immunity are required.

Features:

- Very Low Noise
- Flat Frequency Response
- Small package
- Low Current
- MaxRF protection
- Zero-Height MicTM
- Ultra-Stable Performance
- Standard SMD Reflow
- Omnidirectional



1. ABSOLUTE MAXIMUM RATINGS

Parameter	Absolute Maximum Rating	Units
V _{DD} to Ground	-0.5, +5.0	V
OUT to Ground	-0.3 , $V_{DD} + 0.3$	٧
Input Current to Any Pin	±5	mA
Temperature Range	-40 to +100	°C

Stresses exceeding these "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation at these or any other conditions beyond those indicated under "Acoustic & Electrical Specifications" is not implied. Exposure beyond those indicated under "Acoustic & Electrical Specifications" for extended periods may affect device reliability.

2. ACOUSTIC & ELECTRICAL SPECIFICATIONS

TEST CONDITIONS: 23 \pm 2°C, 55 \pm 20% R.H., $V_{DD}(min) \le V_{DD} \le V_{DD}(max)$, no load, unless otherwise indicated

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Supply Voltage ¹	V_{DD}		1.5	-	3.6	V
Supply Current ^{1,2}	I _{DD}		1	120	165	μΑ
Sensitivity ¹	S	94 dB SPL @ 1 kHz	-41	-38	-35	dBV/Pa
Signal to Noise Ratio	SNR	94 dB SPL @ 1 kHz, A-weighted	1	65	1	dB(A)
Total Harmonic Distortion	THD	94 dB SPL @ 1 kHz, S = Typ, $R_{load} > 2 k\Omega$	-	0.2	-	%
Acoustic Overload Point	AOP	10% THD @ 1 kHz, S = Typ, V_{DD} = 1.8V, R_{load} > 2 k Ω	-	123	-	dB SPL
Power Supply Rejection Ratio	PSRR	100 mVpp sinewave, 20-10 kHz, $V_{DD} = 2.75V$	1	66	1	dB
Power Supply Rejection	PSR	100 mVpp square wave @ 217 Hz, V _{DD} = 1.8V, A-weighted	1	-95	1	dBV(A)
DC Output		$V_{DD} = 1.5V$	-	1.09	-	V
Output Impedance	Z _{OUT}	@ 1 kHz	-	-	400	Ω
Directivity			Omnidirectional		al	
Polarity		Increasing sound pressure	Increasing output voltage			

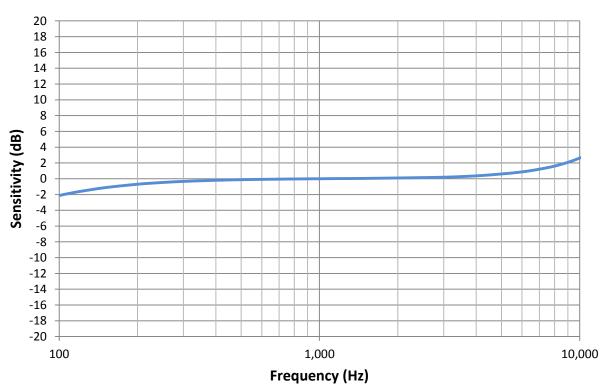
¹100% tested

 $^{^{2}}$ Maximum specifications are measured at maximum V_{DD} . Typical specifications are measured at V_{DD} = 1.8V.



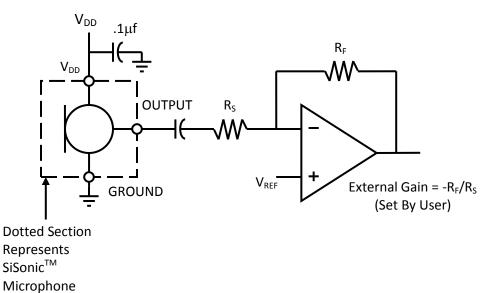
3. FREQUENCY RESPONSE CURVE

Typical Free Field Response Normalized to 1 kHz





4. INTERFACE CIRCUIT

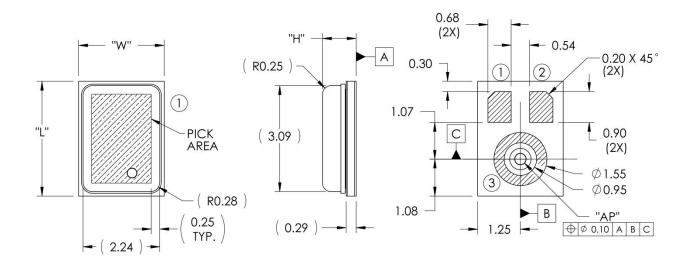


Note: Capacitors near the microphone should not contain Class 2 dielectrics.

Detailed information on acoustic, mechanical, and system integration can be found in the latest SiSonicTM Design Guide application note.



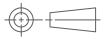
5. MECHANICAL SPECIFICATIONS



Item	Dimension	Tolerance
Length (L)	3.35	±0.10
Width (W)	2.50	±0.10
Height (H)	0.98	±0.10
Acoustic Port (AP)	Ø0.25	±0.05

Pin#	Pin Name	Туре	Description
1	V_{DD}	Power	Power Supply
2	OUTPUT	Signal	Output Signal
3	GROUND	Power	Ground

Notes: Pick Area only extends to 0.25 mm of any edge or hole unless otherwise specified.

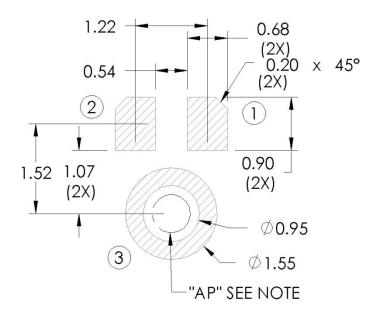


Dimensions are in millimeters unless otherwise specified.

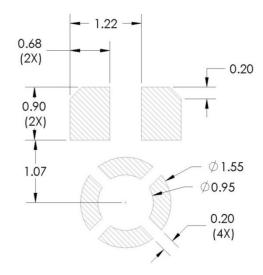
Tolerance is ±0.15mm unless otherwise specified



6. EXAMPLE LAND PATTERN



7. EXAMPLE SOLDER STENCIL PATTERN



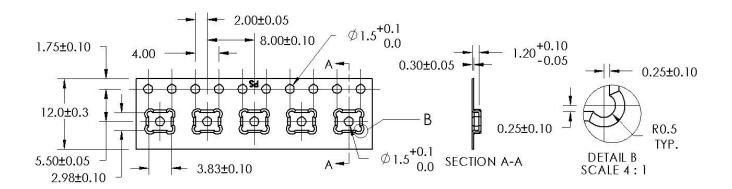
Notes: Dimensions are in millimeters unless otherwise specified.

Detailed information on AP size considerations can be found in the latest $SiSonic^{TM}$ Design Guide application note.

Further optimizations based on application should be performed.



8. PACKAGING & MARKING DETAIL



Model Number	Suffix	Reel Diameter	Quantity Per Reel
SPA2629LR5H-B	-8	13"	5,900

Alpha Character A:

"S": Knowles SiSonicTM Production

"E": Knowles Engineering Samples

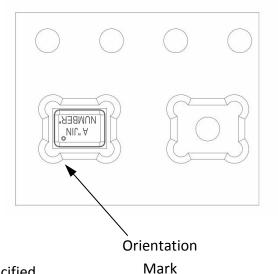
"P": Knowles Prototype Samples

"M": Knowles SiSonicTM Production Malaysia

"C": Knowles SiSonicTM Production China (Suzhou)

"JIN NUMBER":

Unique Job Identification Number for product traceability



Notes: Dimensions are in millimeters unless otherwise specified.

Vacuum pickup only in the pick area indicated in Mechanical Specifications.

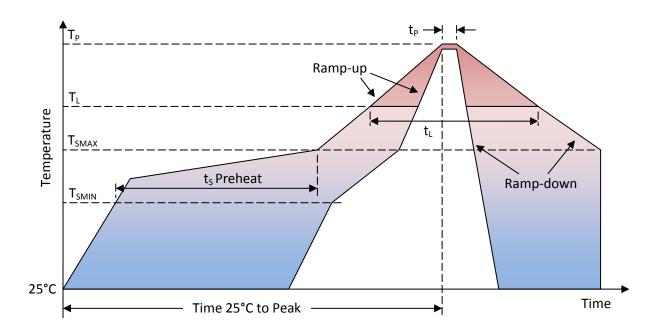
Tape & reel per EIA-481.

Labels applied directly to reel and external package.

Shelf life: Twelve (12) months when devices are to be stored in factory supplied, unopened ESD moisture sensitive bag under maximum environmental conditions of 30°C, 70% R.H.



9. RECOMMENDED REFLOW PROFILE



Profile Feature	Pb-Free	
Average Ramp-up rate (T _{SMAX} to T _P)	3°C/second max.	
Preheat		
 Temperature Min (T_{SMIN}) 	150°C	
 Temperature Max (T_{SMAX}) 	200°C	
 Time (T_{SMIN} to T_{SMAX}) (t_S) 	60-180 seconds	
Time maintained above:		
 Temperature (T_L) 	217°C	
Time (t _L)	60-150 seconds	
Peak Temperature (T _P)	260°C	
Time within 5°C of actual Peak Temperature (t _P)	20-40 seconds	
Ramp-down rate (T _P to T _{SMAX})	6°C/second max	
Time 25°C to Peak Temperature	8 minutes max	

Notes: Based on IPC/JDEC J-STD-020 Revision C.

All temperatures refer to topside of the package, measured on the package body surface.



10. ADDITIONAL NOTES

- (A) MSL (moisture sensitivity level) Class 1.
- (B) Maximum of 3 reflow cycles is recommended.
- (C) In order to minimize device damage:
 - Do not board wash or clean after the reflow process.
 - Do not brush board with or without solvents after the reflow process.
 - Do not directly expose to ultrasonic processing, welding, or cleaning.
 - Do not insert any object in port hole of device at any time.
 - Do not apply over 30 psi of air pressure into the port hole.
 - Do not pull a vacuum over port hole of the microphone.
 - Do not apply a vacuum when repacking into sealed bags at a rate faster than 0.5 atm/sec.

11. MATERIALS STATEMENT

Meets the requirements of the European RoHS directive 2011/65/EC as amended.

Meets the requirements of the industry standard IEC 61249-2-21:2003 for halogenated substances and Knowles Green Materials Standards Policy section on Halogen-Free.

Ozone depleting substances are not used in the product or the processes used to make the product, including compounds listed in Annex A, B, and C of the "Montreal Protocol on Substances That Deplete the Ozone Layer."



12. RELIABILITY SPECIFICATIONS

Test	Description
Thermal Shock	100 cycles air-to-air thermal shock from -40oC to +125oC with 15 minute soaks. (IEC 68-2-4)
High Temperature Storage	1,000 hours at +105oC environment (IEC 68-2-2 Test Ba)
Low Temperature Storage	1,000 hours at -40oC environment (IEC 68-2-2 Test Aa)
High Temperature Bias	1,000 hours at +105oC under bias (IEC 68-2-2 Test Ba)
Low Temperature Bias	1,000 hours at -40oC under bias (IEC 68-2-2 Test Aa)
Temperature / Humidity Bias	1,000 hours at +85oC/85% R.H. under bias. (JESD22-A101A-B)
Vibration	4 cycles of 20 to 2,000 Hz sinusoidal sweep with 20 G peak acceleration lasting 12 minutes in X, Y, and Z directions. (Mil-Std-883E, Method 2007.2 A)
ESD-HBM	3 discharges of ±2 kV direct contact to I/O pins. (MIL 883E, Method 3015.7)
ESD-LID/GND	3 discharges of ±8 kV direct contact to lid while unit is grounded. (IEC 61000-4-2)
ESD-MM	3 discharges of ±200 V direct contact to I/O pins. (ESD STM5.2)
Reflow	5 reflow cycles with peak temperature of +260oC
Mechanical Shock	3 pulses of 10,000 G in the X, Y, and Z direction (IEC 68-2-27, Test Ea)

Notes: After reliability tests are performed, the sensitivity of the microphones shall not deviate more than 3 dB from its initial value.

After 3 reflow cycles, the sensitivity of the microphone shall not deviate more than 1dB from its initial value.



13. SPECIFICATIONS REVISIONS

Revision	Specification Changes	Date
Α	Initial Release (C10115265)	10/02/13
В	Added "M" and "C" laser etch classification on page 7 (ECR 16-651)	2/19/16

Information contained herein is subject to change without notice. It may be used by a party at their own discretion and risk. We do not guarantee any results or assume any liability in connection with its use. This publication is not to be taken as a license to operate under any existing patents.